



NE85639R-T1 Information

Part Number NE85639R-T1

Manufacturer CEL

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - RF

Description TRANS NPN 1GHZ SOT-143R

Package SOT-143R

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









NE85639R-T1 Specifications

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Manufacturer Part Number	NE85639R-T1
Manufacturer	CEL
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - RF
Package	SOT-143R
Series	-
Transistor Type	NPN
Voltage - Collector Emitter Breakdown (Max)	12V
Frequency - Transition	9GHz
Noise Figure (dB Typ @ f)	1.5dB ~ 2.1dB @ 1GHz
Gain	13.5dB
Power - Max	200mW
DC Current Gain (hFE) (Min) @ Ic, Vce	50 @ 20mA, 10V
Current - Collector (Ic) (Max)	100mA
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Package / Case	SOT-143R
Supplier Device Package	SOT-143R
	Report errors?

NE85639R-T1 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

NE85639R-T1 Payment Methods





















NE85639R-T1 Shipping Methods













If you have any question about NE85639R-T1, please do not hesitate to contact us!

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